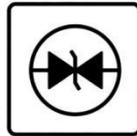


MSKSEMI

SEMICONDUCTOR



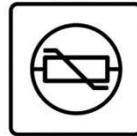
ESD



TVS



TSS



MOV



GDT

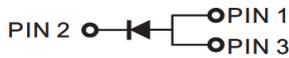


PLED

Product data sheet



TO-277



■ **Features**

- Low forward voltage drop.
- Excellent high temperature stability.
- Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CP10S45SG.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ **Mechanical data**

- Epoxy : UL94-V0 rated flame retardant.
- Case : Molded plastic, TO-277.
- Lead : Solder plated, solderable per MIL-STD-750, Method 2026.
- Polarity: Indicated by cathode band.
- Mounting Position : Any.
- Weight : Approximated 0.093 grams.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

| P/N(MARK) | SB1545L | UNITS |
|--|------------|-------|
| Maximum Recurrent Peak Reverse Voltage | 45 | V |
| Maximum RMS Voltage | 32 | V |
| Maximum DC Blocking Voltage | 45 | V |
| Maximum Average Forward Rectified Current | | |
| See Fig. 1 | 15.0 | A |
| Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method) | 175 | A |
| Maximum Instantaneous Forward Voltage at 15.0A | 0.47 | V |
| Maximum DC Reverse Current Ta=25°C | 0.2 | mA |
| at Rated DC Blocking Voltage Ta=100°C | 20 | mA |
| Typical Junction Capacitance (Note1) | | pF |
| Typical Thermal Resistance R JA (Note 2) | 31 | °C/W |
| Operating Temperature Range Tj | -65 — +150 | °C |
| Storage Temperature Range Tstg | -65 — +150 | °C |

Note : 1.FR-4 PCB, 2oz.Copper.
2.Polyimide PCB, 2oz.Copper.Cathode pad dimensions 18.8mm x 14.4mm.Anode pad dimensions 5.6mm x 14.4mm.

RATING AND CHARACTERISTIC CURVES

Fig. 1 - Forward Power Dissipation

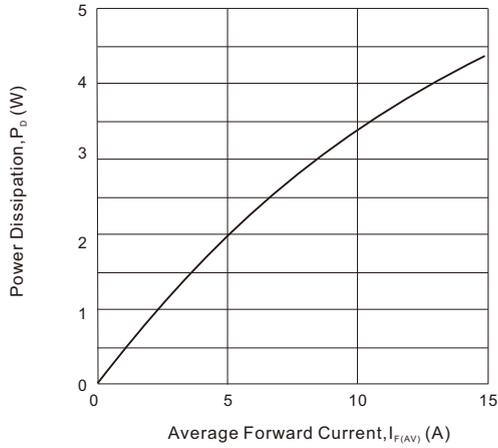


Fig. 2 - Instantaneous Forward Characteristics

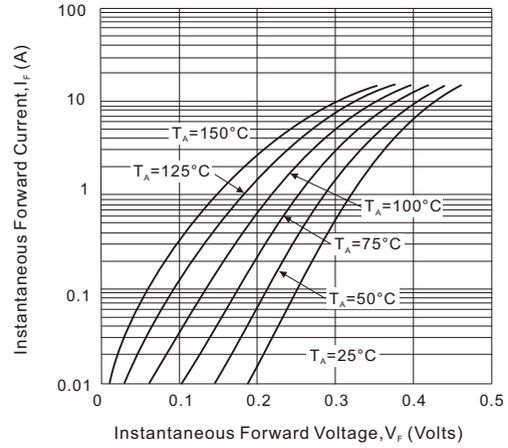


Fig. 3 - Reverse Characteristics

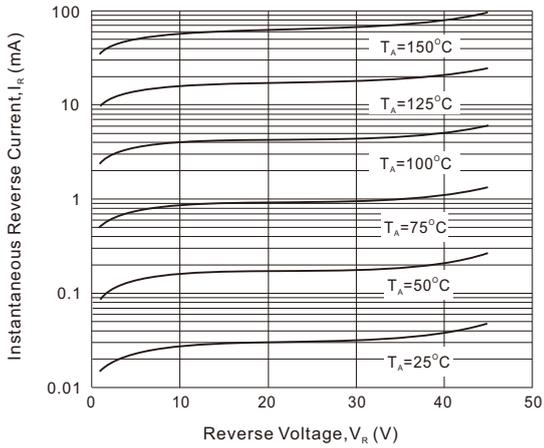


Fig. 4 - Forward Current Derating Curve

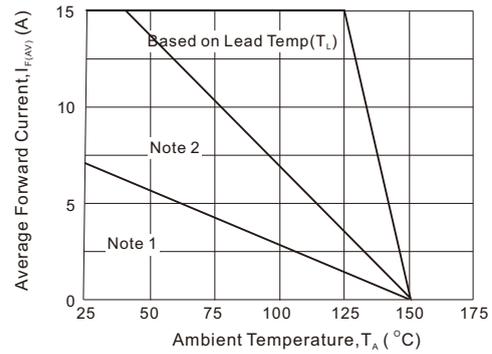


Fig. 5 - Total Capacitance VS. Reverse Voltage

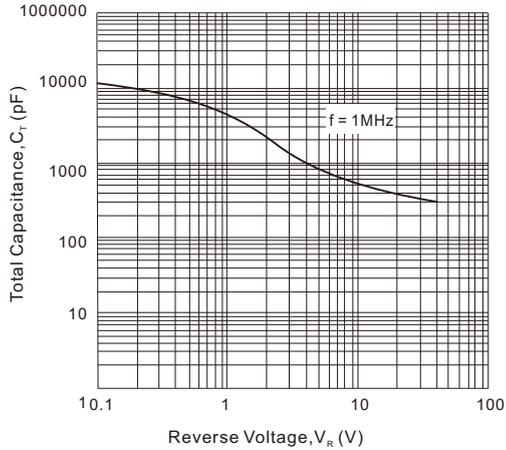
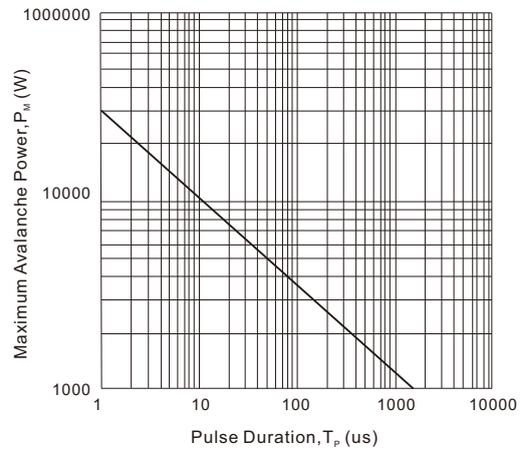
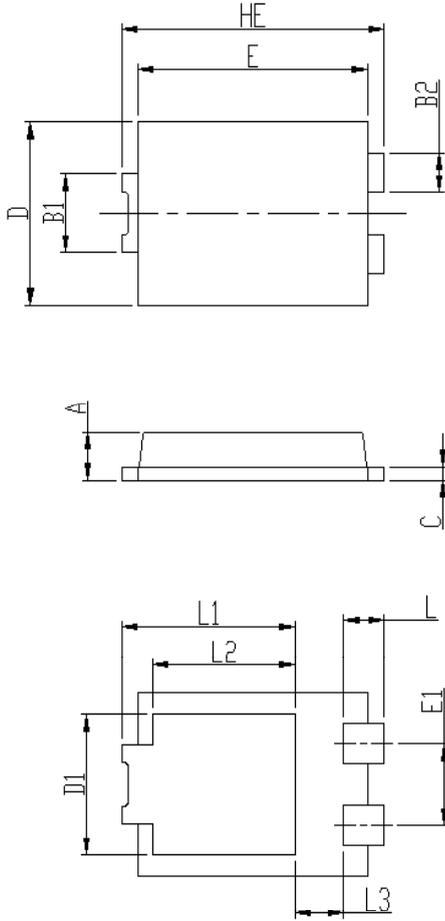


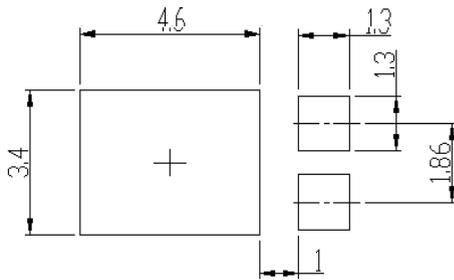
Fig. 6 - Maximum Avalanche Power Curve





| DIM | Unit: mm | | Unit: inch | |
|-----|-----------|-----|------------|-------|
| | MIN | MAX | MIN | MAX |
| HE | 6.4 | 6.6 | 0.252 | 0.260 |
| E | 5.6 | 5.8 | 0.220 | 0.228 |
| D | 4.1 | 4.3 | 0.161 | 0.169 |
| B1 | 1.7 | 1.9 | 0.067 | 0.075 |
| B2 | 0.8 | 1 | 0.031 | 0.039 |
| A | 1.05 | 1.2 | 0.041 | 0.047 |
| C | 0.3 | 0.4 | 0.012 | 0.016 |
| L | 0.85 | 1.1 | 0.033 | 0.043 |
| L1 | 4.2 | 4.4 | 0.165 | 0.173 |
| L2 | 3.52 Typ. | | 0.139 Typ. | |
| L3 | 1.1 | 1.4 | 0.043 | 0.055 |
| D1 | 3 | 3.3 | 0.118 | 0.130 |
| E1 | 1.86 Typ. | | 0.073 Typ. | |

T0-277 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

REEL SPECIFICATION

| P/N | PKG | QTY |
|---------|--------|------|
| SB1545L | TO-277 | 5000 |

Attention

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all MSKSEMI Semiconductor products described or contained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- MSKSEMI Semiconductor strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringement of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the MSKSEMI Semiconductor product that you intend to use.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Schottky Diodes & Rectifiers](#) category:

Click to view products by [MSKSEMI](#) manufacturer:

Other Similar products are found below :

[MA4E2039](#) [MA4E2508M-1112](#) [MBR1545CT](#) [MMBD301M3T5G](#) [RB160M-50TR](#) [D83C](#) [BAS16E6433HTMA1](#) [BAT 54-02LRH E6327](#)
[NRVBAF360T3G](#) [NSR05F40QNXT5G](#) [NTE555](#) [JANS1N6640](#) [SK310-T](#) [SK34B-TP](#) [SS3003CH-TL-E](#) [GA01SHT18](#)
[CRS10I30A\(TE85L,QM](#) [MA4E2501L-1290](#) [MBRA140TRPBF](#) [MBRB30H30CT-1G](#) [BAT 15-04R E6152](#) [JANTX1N5712-1](#) [DMJ3940-000](#)
[SB007-03C-TB-E](#) [SK33B-TP](#) [NRVBB20100CTT4G](#) [NRVBM120LT1G](#) [NTSB30U100CT-1G](#) [VS-6CWQ10FNHM3](#) [CRG04\(T5L,TEMQ\)](#)
[ACDBA1100LR-HF](#) [ACDBA1200-HF](#) [ACDBA240-HF](#) [ACDBA3100-HF](#) [CDBQC0530L-HF](#) [CDBQC0240LR-HF](#) [ACDBA260LR-HF](#)
[ACDBA1100-HF](#) [MA4E2502L-1246](#) [10BQ015-M3/5BT](#) [NRVBM120ET1G](#) [CRS08TE85LQM](#) [PMAD1108-LF](#) [B120Q-13-F](#) [1N5819T-G](#)
[B0530WSQ-7-F](#) [PDS1040Q-13](#) [B160BQ-13-F](#) [SDM05U20CSP-7](#) [B140S1F-7](#)